



# United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/891,682	06/26/2001	Evan George Colgan	YOR9-2001-0004 US1 (8728-	9748	
7590 03/11/2004			EXAM	EXAMINER	
F. CHAU & ASSOCIATES, LLP			QI, ZHI	QI, ZHI QIANG	
Suite 501					
1900 Hempstea	1900 Hempstead Turnpike			PAPER NUMBER	
East Meadow, NY 11554			2871	2871	
			<b>_</b> . <b>_</b> .		

DATE MAILED: 03/11/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	
	09/891,682	COLGAN ET AL.	
Office Action Summary	Examiner	Art Unit	
	Mike Qi	2871 JW	
The MAILING DATE of this communication ap	pears on the cover sheet with the o	correspondence address	
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a rep  - If NO period for reply is specified above, the maximum statutory period  - Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be tirely within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from e, cause the application to become ABANDONE	nely filed /s will be considered timely. If the mailing date of this communication. ED (35 U.S.C. § 133).	
Status			
<ul> <li>1) Responsive to communication(s) filed on 13 №</li> <li>2a) This action is FINAL.</li> <li>2b) This</li> <li>3) Since this application is in condition for allowed closed in accordance with the practice under the condition of the cond</li></ul>	s action is non-final.  ance except for formal matters, pro		
Disposition of Claims			
<ul> <li>4) ⊠ Claim(s) 1-14 and 16-22 is/are pending in the 4a) Of the above claim(s) is/are withdra</li> <li>5) ☐ Claim(s) is/are allowed.</li> <li>6) ☒ Claim(s) 1-5 and 8 is/are rejected.</li> <li>7) ☒ Claim(s) 6,7 and 22 is/are objected to.</li> <li>8) ☒ Claim(s) 9-14 and 16-21 are subject to restrict</li> </ul>	wn from consideration.		
Application Papers			
9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) acc Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Examine 11.	cepted or b) objected to by the drawing(s) be held in abeyance. Section is required if the drawing(s) is ob	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).	
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureat * See the attached detailed Office action for a list	ts have been received. ts have been received in Applicat prity documents have been receive tu (PCT Rule 17.2(a)).	ion No ed in this National Stage	
Attachment(s)  1) Notice of References Cited (PTO-892)  2) Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail D  5) Notice of Informal F 6) Other:		

Art Unit: 2871

#### **DETAILED ACTION**

### Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claim 1 is rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant admitted prior art (AAPA) in view of US 5,766,493 (Shin) and JP 9-230317 (Katsuhiko et al).

Claim 1, AAPA discloses (page 1, line 14 – page 9, line 5; Fig.1) that a method of fabricating a collimate and post diffuse type liquid crystal cell comprising:

- first substrate (TFT substrate) (9), second substrate (color filter substrate) (7), having same thickness, such as 0.7 mm;
- lapping the first substrate and concurrently lapping the second substrate;
- polishing the first and second substrates.

AAPA also disclosed (page 2, lines 18 –24) that the bulk of the material is removed by lapping using rough abrasive compounds. Therefore, the material would be removed more in a faster lapping rate, and the material would be removed less in a slower lapping rate.

Art Unit: 2871

AAPA does not expressly disclose making the first substrate and the second substrate having different thickness by lapping the first substrate at a first rate and lapping the second substrate at a second rate, and the thinner substrate is on the viewer side of the liquid crystal cell.

However, Shin discloses (col.3, lines 30 – 41) that the upper and lower substrates can have different thickness. The thinner substrate would have good light transmittance, the thicker substrate would prevent cracks. Therefore, using thinner substrate on the viewer side of the liquid crystal cell would increase the light transmittance, and increasing the display brightness; and using thicker substrate on the support side of the liquid crystal cell would prevent the cracks during assembly process. Inherently, the thinner substrate must be on the viewer side of the liquid crystal cell as to increase the light transmittance.

Although AAPA and Shin do not expressly disclose that providing the thinner of the first and second substrates on a viewer side of the collimate and post diffuse type liquid crystal cell to reduce depixelization, but in order to increase the transmittance, to provide thinner substrate on the viewer side of the liquid crystal cell that is an inherent property and obviousness.

However, Katsuhiko (JP 9-230317) discloses (abstract; Fig.1) that forming the transparent substrate on an observation side (viewer side) is thinner than the transparent substrate on a back surface side so as to improve resolution, to increase brightness and to make screen display with improved image quality.

Therefore, it would have been obvious to those skilled in the art at the time the invention was made to use a first lapping rate for lapping the first substrate

Art Unit: 2871

thinner and to use a second lapping rate for lapping the second substrate thicker so as to have different thickness for the first and the second substrates as claimed in claim 1, since the thinner substrate would increase the display brightness and the thick support substrate would prevent cracks during the assembly process, and proving the thinner substrate on the viewer side so as to increase the image clarity and brightness efficiency and to improve the resolution.

3. Claims 2-5 and 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant admitted prior art (AAPA), US 5,766,493 (Shin) and JP 9-230317 (Katsuhiko et al) as applied to claim 1 above, and further in view of "Development of a Manufacturing Process for a Thin, Lightweight LCD Cell" (Ohkuma et al).

Claims 2-4, Shin discloses (col.3, lines 30 - 41) that the upper and lower substrates can have different thickness. The thinner substrate would have good light transmittance, the thicker substrate would prevent cracks.

Still laking is the limitation such that thinning by lapping and polishing, and using an abrasive material.

However, Ohkuma discloses (Fig.2) that the LCD cell thinning by lapping and polishing, and using an abrasive material on a plate and rotating the plate to lap the substrates. The faster lapping rate would remove more material than the slower lapping rate.

Therefore, it would have been obvious to those skilled in the art at the time the invention was made to use greater lapping rate for lapping the color filter

Art Unit: 2871

substrate and to use slower lapping rate for lapping the TFT substrate, in order to make a thinner color filter substrate and a thicker TFT substrate as claimed in claims 2-4, since the thinner substrate would increase the display brightness and thicker substrate would prevent the cracks, especially the TFT substrate has more electrical connections need to be protected and reducing the breakage occurrence.

Claim 5, AAPA discloses (page 2, lines 8-25) that using 0.7 mm thick array glass substrate and 0.7 mm thick color filter substrate, i.e., the same thickness of 0.7 mm.

Claim 8, AAPA discloses (page 2, lines 8-25) that polishing is used to make both sides of the cell smooth, and generally, making equal thinning for both the array glass and the color filter glass, therefore, the polishing must be performed at a same polishing rate in order to obtain the equal thinning.

# Allowable Subject Matter

- 4. Claims 6-7 and 22 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 5. Claims 9-14,16 and 17-21 are allowed.
- 6. The following is a statement of reasons for the indication of allowable subject matter:

The prior art of record neither discloses nor teaches a method for

Art Unit: 2871

fabricating a collimate and post diffuse type liquid crystal cell comprising various steps and a collimate and post diffuse type liquid crystal cell comprising various elements as claimed, more specifically, as the following:

the different thickness for the color filter substrate and the TFT array substrate are 0.4 mm and 0.6 mm respectively [claim 6];

the step of providing the thinner of the first and second substrates includes the step of providing a depixelization ratio of less than about 2.0; and further the depixelization ratio of less than about 1.6 [claims 7 and 22];

the step of providing the thinner of the first and second substrates on a viewer side of the collimate and post diffuse type liquid crystal cell to reduce depixelization and to provide depixelization ratio of less than about 1.6 [claim 9];

the thickness of the color filter substrate is less than the thickness of the TFT array substrate to provide a depixelization ratio of less than about 1.6 [claim 17];

The color filter substrate including a thickness which is less than a thickness of the thin film transistor array substrate to provide a depixelization ratio less than about 2.0 [claim 21].

The closest references AAPA, Shin and Ohkuma disclose a collimate and post diffuse type liquid crystal cell wherein the upper and lower substrates having different thickness and using lapping and polishing to make the substrate thinning, but the prior art of records do not disclose the color filter substrate has 0.4 mm thickness and the TFT array substrate has 0.6 mm thickness as claimed in claims 6; and most references indicate thinning the thickness less than 0.5 mm

Art Unit: 2871

would be very difficult, because more thin substrate would be very easy to be broken and get cracks. The prior art of records also do not disclose the thinner color filter substrate and the thicker TFT array substrate would provide a depixelization ratio of less than about 2.0 and 1.6 as claimed in claims 7,22,9,17 and 21.

# Response to Arguments

7. Applicant's arguments with respect to claims 1-14,16-22 have been considered but are moot in view of the new ground(s) of rejection.

### Conclusion

- 8. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.
- 9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Mike Qi whose telephone number is (571) 272-2299. The examiner can normally be reached on M-T 8:00 am-5:00 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert Kim can be reached on (571) 272-2293. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Page 8

Application/Control Number: 09/891,682

Art Unit: 2871

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Mike Qi February 24, 2004

> TARIFUR R. CHOWDHURY PRIMARY EXAMINER